2SA1786: PNP Epitaxial Planar Silicon Transistor 2SC4646: NPN Triple Diffused Planar Silicon Transistor

2SA1786/2SC4646



High Voltage Driver Applications

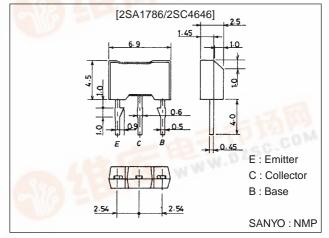
Features

- · Large current capacity (I_C=2A).
- · High breakdown voltage (V_{CEO}≥400V).

Package Dimensions

unit:mm

2064



(): 2SA1786

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)400	V
Collector-to-Emitter Voltage	VCEO		(-)400	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	l _C		(-)2	А
Colletor Current (Pulse)	ICP	- s.b. ((-)4	А
Collector Dissipation	PC	A 141 15	1	W
Junction Temperature	Tj	ASS LEL	150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)300V, I _E =0			(–)1.0	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(–)1.0	μΑ
DC Current Gain	hFE	V _{CE} =(-)10V, I _C =(-)100mA	40*		200*	The state of
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)100mA		(40)60	7	MHz
Output Capacitance	C _{ob}	V _{CB} =(-)30V, f=1MHz		(25)15	80.	pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)500mA, I _B =(-)50mA	W.M.		(–)1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)500mA, I _B =(-)50mA			(-)1.0	V

*: The 2SA1786/2SC4646 are classified by 100mA hFE as follows:

40 C 80 60 D 120 100 E 200

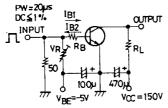
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SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

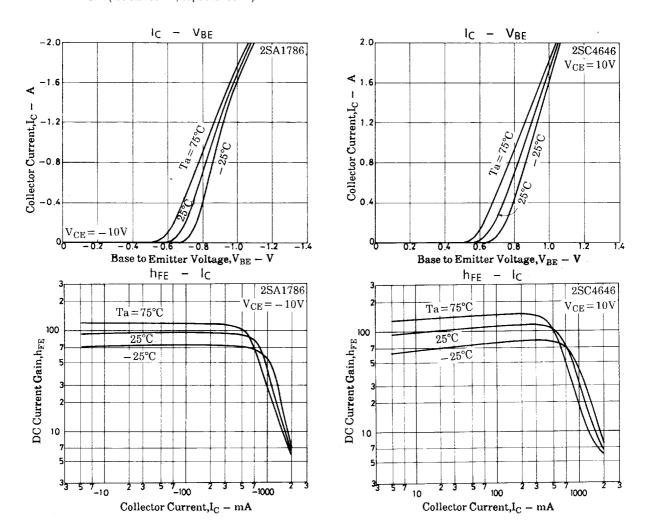
2SA1786/2SC4646

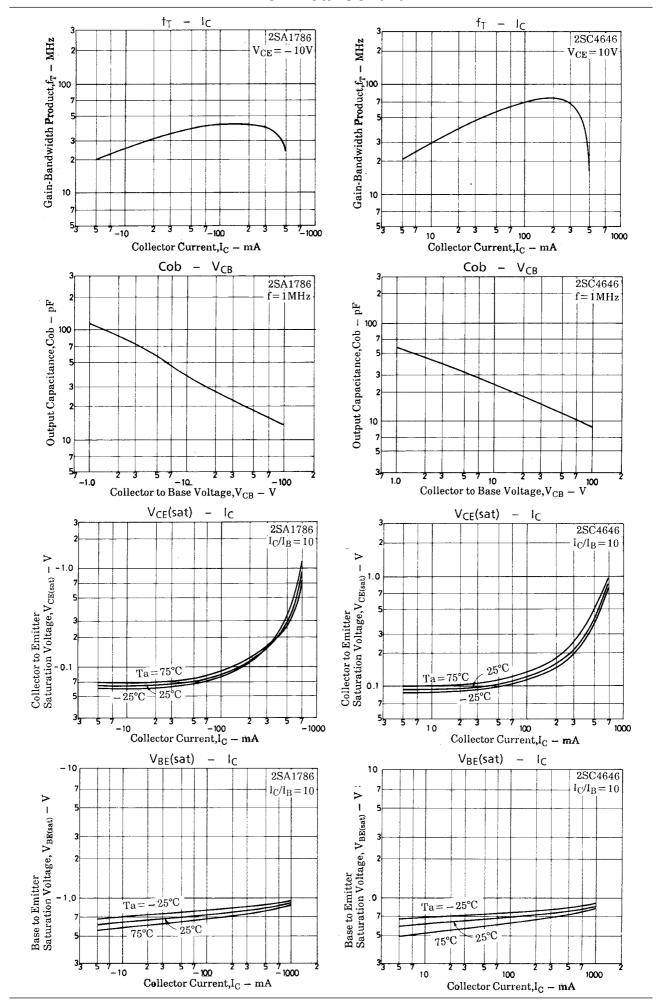
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V _(BR) CBO	$I_{C}=(-)10\mu A, I_{E}=0$	(–)400			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(–)1mA, R _{BE} =∞	(-)400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	$I_{E}=(-)10\mu A, I_{C}=0$	(–)5			V
Turn-ON Time	t _{on}	See specified Test Circuit.		(0.12)		μs
				0.085		μs
Storage Time	t _{stg}	See specified Test Circuit.		(3.0)		μs
				4.0		μs
Turn-OFF Time	toff	See specified Test Circuit.		(0.3)		μs
				0.6		μs

Switching Time Test Circuit

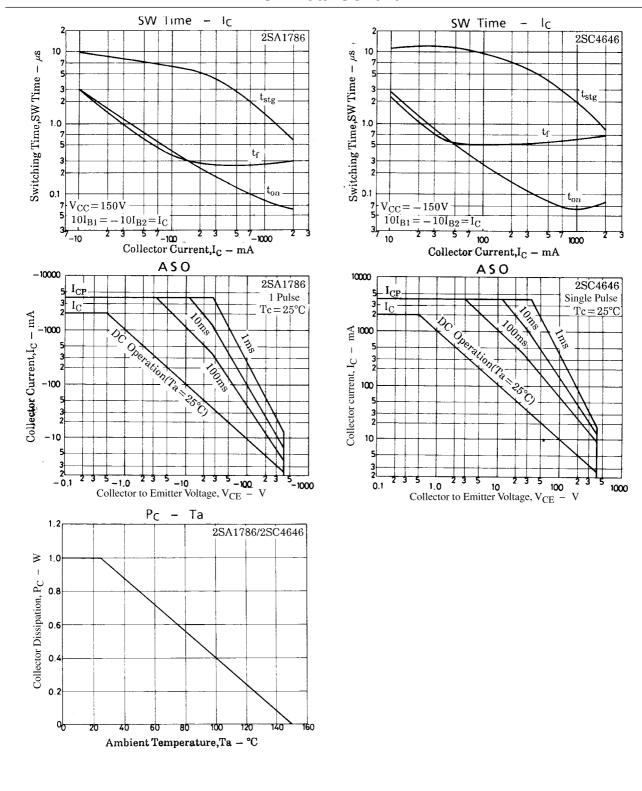


 $\begin{array}{l} 10I_{B1}=-10I_{B2}=I_{C}=500mA\\ R_{L}=300\Omega,\,R_{B}=20\Omega,\,at\,I_{C}=500mA\\ (For\,PNP,\,the\,polarity\,is\,reversed.)\\ Unit\,(resistance:\Omega,\,capacitance:F) \end{array}$





2SA1786/2SC4646



2SA1786/2SC4646

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